



Implementing an LCD TV Power Supply with the NCP1396A, NCP1605, and NCP1027

Prepared by Roman Stuler

Introduction

This document provides a detailed description of the implementation of an LCD TV power supply. The LDC TV supply unit exhibits high efficiency, low EMI noise and a low profile construction. The board contains DCM/CCM PFC front stage, 210 W LLC power stage and 12.5 W standby flyback converter.

The design requirements for our LCD TV power unit are as follows:

| Requirement | Min | Max | Unit |
|---|-----|-------|------|
| Input Voltage | 90 | 265 | Vac |
| Output Voltage 1 | - | 12 | Vdc |
| Output Current 1 | 0 | 3 | A |
| Output Voltage 2 | - | 24 | Vdc |
| Output Current 2 | 0 | 6 | A |
| Output Voltage 3 | - | 30 | Vdc |
| Output Current 3 | 0 | 1 | A |
| Output Voltage Standby Output | - | 5 | Vdc |
| Output Current Standby Output | 0 | 2.5 | A |
| Total Output Power | 0 | 222.5 | W |
| Total No Load Consumption for 0.5W Load on the Standby Output | - | 1 | W |

NOTE: Only 24 V output is regulated in this version of the board. Additional output(s) regulation can be assured by adding feedback resistors to desired output (or outputs for percentage weight).

The NCP1396A resonant mode controller has been selected for this application because the soft-start absence on the fast fault input offers an easy implementation of the skip cycle mode. This helps to assure regulation of the resonant converter under no load conditions. The NCP1396A offers many other features that are advantageous for our application.

Brown-Out (BO) Protection Input

The input voltage of the resonant converter, when divided down, is permanently monitored by the Brownout pin. If the voltage on the bulk capacitor falls outside of the desired operating range, the controller drive output will be shut off. This feature is necessary for an LLC topology that uses PFC stage without PFC OK control output. In our case the BO input is used as an enabling input and is fully controlled by the front stage controller output (PFC OK).

Timer Based Fault Protection

The converter stops operation after a programmed delay when the protection is activated. This protection can be implemented as a cumulative or integrating characteristic. Thus, under transient load conditions the converter output will not be turned off, unless the extreme load condition exceeds the timeout.

Common Collector Optocoupler Connection

The open collector output allows multiple inputs on the feedback pin i.e. over current sensing circuit, over temperature sensor, etc. The additional input can pull up the feedback voltage level and take over the voltage feedback loop.

600 V High Voltage Floating Driver

The high side driver features a traditional bootstrap circuitry, requiring an external high-voltage diode for the capacitor refueling path. The device incorporates an upper UVLO circuitry that guarantees enough V_{gs} is available for the upper side MOSFET.

Adjustable Dead-Time (DT)

Due to a single resistor wired between DT pin and ground, the user has the option to include needed dead-time, helping to fight cross-conduction between the upper and the lower transistor.

Adjustable Minimum and Maximum Frequency Excursion

Using a single external resistor, the designer can program its lowest frequency point, obtained in lack of feedback voltage (during the startup sequence or in short-circuit conditions). Internally trimmed capacitors offer a $\pm 3\%$ precision on the selection of the minimum switching frequency. The adjustable maximum frequency is less precise ($\pm 15\%$). Please refer to the NCP1396A/B data sheet for detailed description of all mentioned and additional features.

Detailed Demo Board Connection Description

A schematic of the proposed LCD TV power supply is shown in Figure 1. As already mentioned, the supply contains three blocks: a PFC front stage, an LLC converter and an auxiliary flyback converter that powers a TV set during standby and provides bias power for PFC and LLC control circuits during normal operation.

PFC Front Stage

The NCP1605 (IC₁) PFC controller is used for PFC front stage control. This front stage works either in fixed frequency discontinues mode or critical conduction mode depends on the line and load conditions. Capacitors C₄₂, C₃₀, CY₁, CY₂ with common mode choke L₉, inductors L₆, L₇ and varistor R₂₈ form the EMI filter, which suppresses noise conducted to the mains. A bridge rectifier B₁ is used to rectify the input AC line voltage. Capacitor C₅ filters the high frequency ripple current, which is generated by the PFC operation. In this application a classical PFC boost topology is used. The PFC power stage is formed by inductor L₂, MOSFET switch Q₂, diode D₄, bulk capacitors C₆, C₇ and inrush current bypassing diode D₂. The current in the PFC stage is monitored by current sense network R₁₃, R₁₄ and R₁₅. Right input voltage operating range is adjusted by the Brown Out sensing network R₂, R₅, R₁₀, R₁₆, R₃₆ and C₂₁. Output voltage of the PFC stage is regulated to a nominal 395 Vdc via the feedback network R₃, R₆, R₁₁, R₂₂, R₂₉ and R₃₀. Sensing network described above is also used to monitor an overvoltage condition on the PFC output using the NCP1605 OVP pin. PFC regulation loop bandwidth is limited by the capacitor C₂₂. The sensitivity of the zero current detection circuitry is given by the resistor R₃₉ value. Capacitor C₁₉ and resistor R₄₀ are used to control the maximum Q₂ switch on-time. Capacitor C₂₄ dictates the DCM operating frequency. Skip mode of the PFC front stage is initiated by the NCP1605 controller when the voltage on the STBY pin is lower than 0.3 V. Since the LLC stage voltage feedback and also bulk capacitor voltage have opposing reaction function (increasing when output load decreases), the divided (R₃₅, R₄₃ and C₂₅) LLC stage primary current information has been used to trigger the PFC skip mode during light load conditions.

The controller receives the V_{CC} voltage from standby stage when standard operation mode is enabled by the TV set application.

Please refer to the application note AND8281/D for a detailed explanation on how to design a PFC front stage using the NCP1605 controller.

Standby Supply

An ON Semiconductor NCP1027 monolithic switcher (IC₅) is used for auxiliary (or standby) power stage provide a cost effective solution, needed output power and low standby consumption, since this switcher offers skip mode capability under light load conditions. The nominal output power of this converter is 12.5 W. The unit is connected directly to the bulk capacitors so during standby conditions it operates from rectified mains. During normal operating conditions the switcher is energized by higher voltage (PFC front stage is working). After the start (that is assured by internal current supply) the switcher is powered from the auxiliary winding. Diode D₂₃ is used for rectification and capacitor C₄₇ to filter auxiliary voltage. Resistor R₇₁ limits the I_{CC} current so the auto-recovery OVP is not activated for the correct V_{CC} voltage. The appropriate operating bulk

voltage range is restricted by the Brown Out sensing network R₆₄, R₆₈, R₇₀, R₇₇ and C₄₈. The NCP1027 switcher features adjustable ramp compensation capability - resistor R₇₈. Feedback loop is accomplished in the standard way: the output voltage level is regulated by the IC₆ to the value which is defined by resistors R₇₄ and R₈₀. Bias current for optocoupler OK₃ and regulator is provided from the standby supply output using resistors R₇₂ and R₇₃. Resistors R₇₅ and R₇₉ are used to stabilize the maximum output power level with bulk voltage evaluation (CS comparator delay compensation). A standard RCD voltage clamp (R₆₆, R₆₇, C₄₁, D₂₁) is installed on the switcher drain to limit its voltage to safe level. There is an optional layout on the board so the TVS (D₁₉) can be used instead of the RCD clamp. This solution further decreases standby power consumption, however, price is slightly higher. Voltage from auxiliary winding, which is used to power the switcher is also used to feed up the PFC front stage and the main LLC converter control circuits. This voltage is limited by a simple zener regulator (D₂₂, Q₇, R₇₆ and C₄₆) and can be inhibited by the OK₂ action. Standby mode can be activated either by positive or negative logic signals (Q₅ or Q₆ assembled). Please refer to the application note AND8241/D for a detailed explanation on how to design a Standby flyback converter using the NCP1027 switcher.

LLC Power Stage

As previously mentioned, the NCP1396A (IC₃) resonant mode controller is used to control the main SMPS unit. The power stage of the LLC converter is formed by bulk capacitors C₆, C₇, MOSFETs Q₁, Q₃, transformer TR₁ and resonant capacitor C₁₁. MOSFETs are driven directly by the controller. Resistors R₁₉ and R₂₀ damp the gate charging circuit to suppress overshoots on the gates and regulate EMI noise. Bootstrap diode D₁₄ is charging the bootstrap capacitor C₂₈ via resistor R₄₂. The bootstrap capacitor powers a floating driver when high side MOSFET is turned on. Safety resistors R₄ and R₁₂ are used to protect MOSFETs (during the experiments on the bench, for instance, when IC₃ is removed).

Center-tapped windings on 12 V and 24 V outputs increase the converter efficiency. A bridge rectifier is used for 30 V output. Different shottky diode types (D₃ with D₅, D₆ through D₁₀ and D₁₁) are used for secondary rectification according to output voltage, power losses and also short circuit capability (not to damage diode during hard short on the output). The low ESR, high temperature electrolytic capacitors C₁ through C₄, C₈ through C₁₀, C₁₂ through C₁₆, together with inductors L₁, L₄, and L₅ serve as filters for corresponding outputs. The secondary voltage regulator IC₂ regulates the output voltage to 24 V, which is value adjusted by resistor divider composed by R₂₄, R₄₈ and R₄₉. If needed, there can be optionally used feedback from other secondary output(s) (R₂₆ and R₂₇ are included in the board layout). On the primary side, the optocoupler works in the connection with a common collector which also allows an easy implementation of the current regulation loop. Maximum

current through the optocoupler transistor is adjusted by a resistor R₃₃. To speed up the regulation response, resistor R₄₇ is connected to the feedback pin.

Capacitor C₃₄ defines the soft start length. Note that the current regulation loop is used in this power stage so it takes control during the startup and affects the soft start action. Resistors R₅₃, R₅₅ and R₅₇ define maximum operating frequency, minimum operating frequency and dead time. The operation/fault time period during the overload is dictated by C₃₅ and R₅₄ values.

The LLC power stage operation is conditioned to the correct PFC front stage operation indicated by the PFC OK signal. This signal, divided down by resistors R₃₂ and R₅₆, enables the NCP1396A controller when the bulk voltage is in the right range (PFC stage reached regulation).

Resistor divider R₅₁ and R₅₈ with bypass capacitor C₃₇ are used to prepare skip mode during light or no load conditions on the power stage output. This skip mode limits the maximum needed operating frequency of the converter and improves no load efficiency of the LLC stage.

As already mentioned, the current feedback loop is used in this design. It limits the primary current of the power stage during overload and helps to implement hick-up mode. Primary current is sensed using charge pump R₁₇, C₁₈, D₁₂, D₁₃. Output of this charge pump is divided and filtered by R₃₁, R₁₈ and C₁₇. Maximum value of this voltage (and thus also the primary current) is regulated to 1.24 V by IC₄ regulator. The compensation of current regulation loop is accomplished by C₃₁ capacitor. Zener diode D₁₅ is used to lower maximum voltage on IC₄. Since we need to bring up the NCP1396 feedback pin to increase the operating frequency during overload, transistor Q₄ with resistors R₃₈ and R₄₄ are used to perform inversion. Output voltage on the Q₄ collector is limited by zener diode D₁₈ to 7.5 V maximally. This voltage divided down by resistors R₅₂ and R₅₉ triggers the slow fault input in case of an overload and also drives the NCP1396A feedback pin via diode D₁₇. This diode assures that the slow fault input is not triggered during light load conditions and in skip mode when the IC₃ feedback pin voltage is pushed up by the voltage feedback loop.

Controller IC₃ receives the V_{CC} voltage from standby stage during normal operation mode. Auxiliary winding of the resonant transformer W₇ (when half wave rectified by D₁) helps to power the control circuits when load on the standby supply output is too low and there is a lack of voltage on the standby auxiliary winding due to pure flyback transformer coupling. Please note that all outputs of the converter (including standby stage) are referenced to one secondary ground (S_GND).

LLC Transformer and Resonant Tank

A transformer from the standard production of the Pulse engineering company has been used for this design. This transformer, which is specially designed for LLC

converters, offers extra high leakage inductance value thanks to a special windings arrangement (see demo board photo in Figure 24). The leakage inductance serves as a resonant inductance, which results in a cost effective solution since no additional inductor is needed to form a resonant tank. Specified parameters of the mentioned transformer are as follows:

| | |
|-------------------------------|-------------------------|
| Leakage (Resonant) Inductance | L _s = 115 μH |
| Magnetizing Inductance | L _m = 450 μH |
| Primary Turns Count | 38 |
| 24 V Output Turns Count | 4 |
| 12 V Output Turns Count | 2 |
| 30 V Output Turns Count | 5 |
| Auxiliary Winding Turns Count | 3 |
| Lm/Ls Ratio | 450/115 = 3.9 |

Low value of the L_m/L_s ratio together with high turns ratio of the transformer will result in the high gain values.

Note that the manufacturer specifies the L_s inductance in a standard way - all secondary windings are shorted during the L_s measurements. This approach is OK for a transformer that has one secondary winding, but in our case we have three different secondary windings and two of them are center taped so only one of the corresponding winding participates on the resonance during one half of the switching period. As a result, the real leakage inductance that participates on the resonance is higher. Due to this fact, the simulation results of gain characteristics that are accomplished based on the transformer datasheet values, are not accurate enough to determine operating frequency range of the proposed converter.

The most accurate method how to obtain gain characteristics of the LLC converter that uses integrated transformer solution with multiple outputs, is to use a gain-phase analyzer. To do so it is necessary to load measured transformer outputs by equivalent AC resistances before measurements (first fundamental approximation - see [5] and [6]). For the center taped windings connect the AC resistance only to one of the windings of the pair - this will happen in reality - only one diode conducts the current during one half of the switching period. The AC resistance for corresponding output can be calculated using Equation 1.

$$R_{ac} = \frac{8}{\pi^2} \frac{V_{out} + V_f}{I_{out}} \tag{eq. 1}$$

Where:

V_{out} is the DC output voltage for given output

V_f is the rectifier forward voltage

I_{out} is the DC output current from given output

The output current has to be selected based on what type of gain characteristics one wants to obtain - full load, 10% load etc. Connection of the transformer during the gain characteristics measurements can be seen in Figure 2.

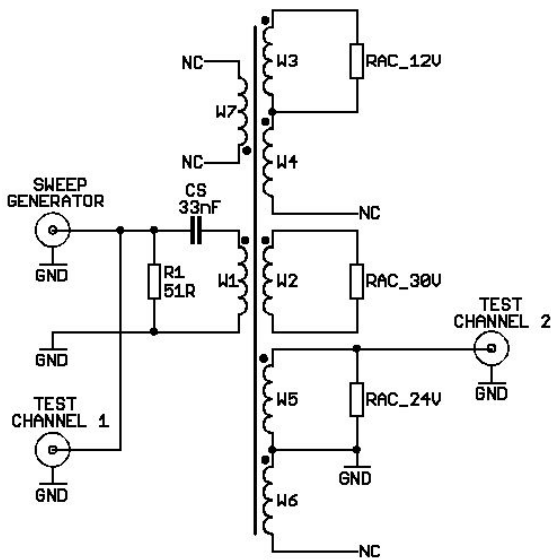


Figure 2. Transformer Connection During Gain Characteristics Measurements

The resonant tank quality factor of $Q = 4.3$ (that corresponds to resonant capacitor $C_r = 33 \text{ nF}$) has been selected for this design in order to narrow operating frequency range of the converter.

The measured full load gain characteristic for the selected resonant tank components and 24 V output can be observed in Figure 3.

The gains that are needed to assure line regulation can be calculated using Equations 2 through 4:

$$G_{\min} = \frac{2(V_{\text{out}} + V_f)}{V_{\text{inmax}}} = \frac{2(24 + 0.6)}{425} = 0.116 \quad (\text{eq. 2})$$

$$G_{\text{nom}} = \frac{2(V_{\text{out}} + V_f)}{V_{\text{innom}}} = \frac{2(24 + 0.6)}{395} = 0.125 \quad (\text{eq. 3})$$

$$G_{\max} = \frac{2(V_{\text{out}} + V_f)}{V_{\text{inmax}}} = \frac{2(24 + 0.6)}{350} = 0.141 \quad (\text{eq. 4})$$

Theoretical series resonant frequency can also be calculated based on the Equation 5:

$$f_{r1} = \frac{1}{2 \cdot \pi \cdot \sqrt{L_r \cdot C_r}} \quad (\text{eq. 5})$$

$$= \frac{1}{2 \cdot 3.14 \cdot \sqrt{115 \cdot 10^{-6} \cdot 33 \cdot 10^{-9}}} = 81.7 \text{ kHz}$$

Now, when looking back to the gain characteristic in Figure 3, the operating conditions of the full loaded LLC power stage can be read:

- The nominal operating frequency of such converter is 94.6 kHz (for nominal bulk voltage)

- The minimum needed operating frequency to assure low line regulation is 79 kHz
- The maximum needed operating frequency to assure high line regulation is 106 kHz
- The converter will operate in the calculated series resonant frequency for $V_{\text{bulk}} = 360 \text{ VDC}$

As demonstrated, the converter will operate above the calculated theoretical series resonant frequency for nominal bulk voltage and full load. The ZCS capability is thus not achieved on the secondary diodes. Also the needed operating frequency range of this converter is very narrow, which is beneficial for LCD TV application - EMI radiation and filtering.

Gain characteristic of this converter for $I_{\text{load}} = 0.10 \cdot I_{\text{max}}$ and same parameters as above is in Figure 4.

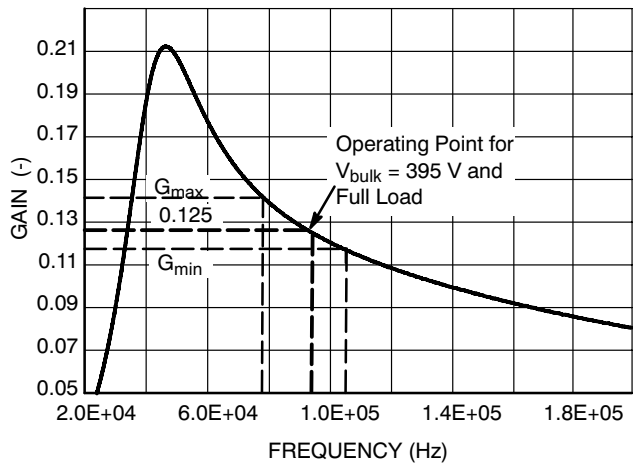


Figure 3. Full Load Gain Characteristic for Full Load and $Q = 4.3$ ($C_r = 33 \text{ nF}$)

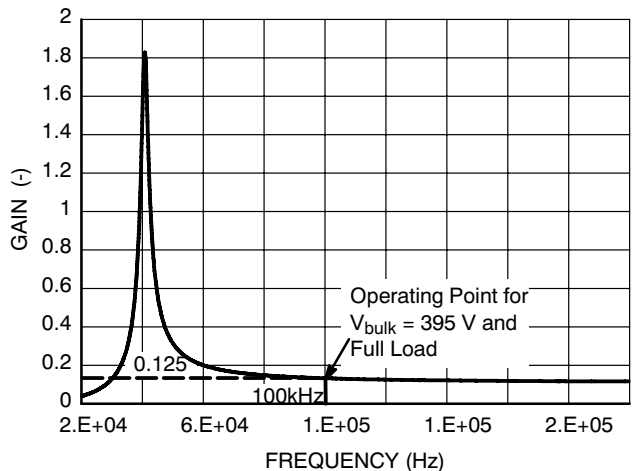


Figure 4. LLC Converter gain Characteristic for 10 % Load Conditions

This characteristic shows that the operating frequency has to be increased above 100 kHz to maintain regulation under light load conditions. Skip mode for the LLC stage can thus be easily implemented when maximum frequency is limited by F_{max} adjust resistor value.

Please refer to the application notes AND8255/D and AND8257/D for further information about the LLC converter resonant tank components design.

Results Summarization

Operating frequency of real LLC stage is 96.1 kHz for full load and $V_{bulk} = 395$ VDC, which is very close to the theoretical expectations. Output current level during which the skip mode takes place (LLC stage) has been set approximately to 8 W by R_{50} , R_{57} divider. The PFC stage enters skip mode for output power lower than 25 W and leaves it for $P_{out} > 30$ W.

Measured efficiency for different input voltages and load conditions can be seen in Figures 5 and 6.

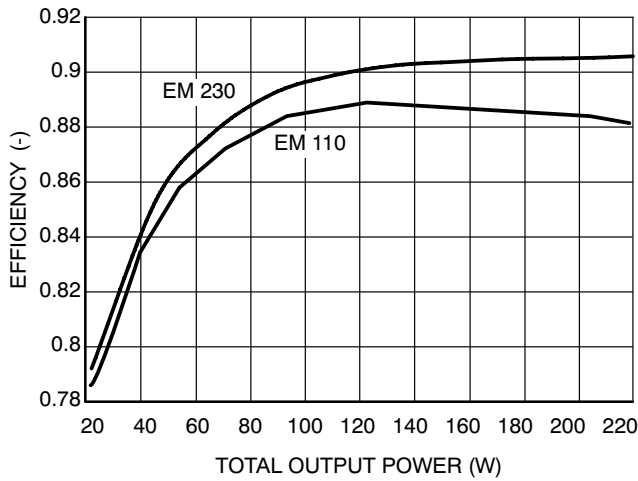


Figure 5. Total Efficiency versus Output Power and Line

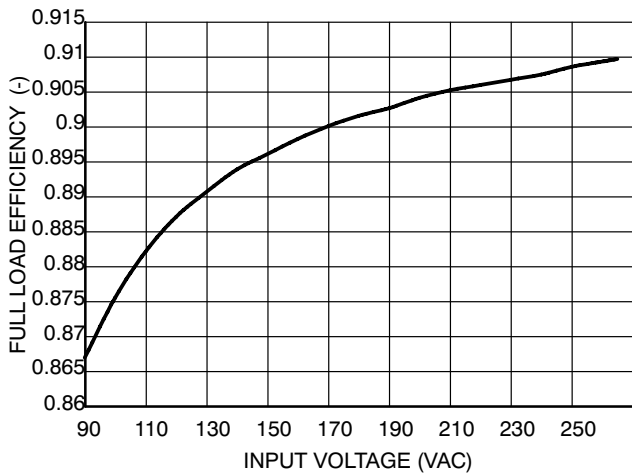


Figure 6. Total Full Load Efficiency versus Input Voltage

Standby (PFC and LLC disabled) consumption characteristic with line voltage for 0.5 W load on the standby output is in Figure 7. The consumption is below 1 W for any input voltage so today’s energy agency’s needs are easily met thanks to this design.

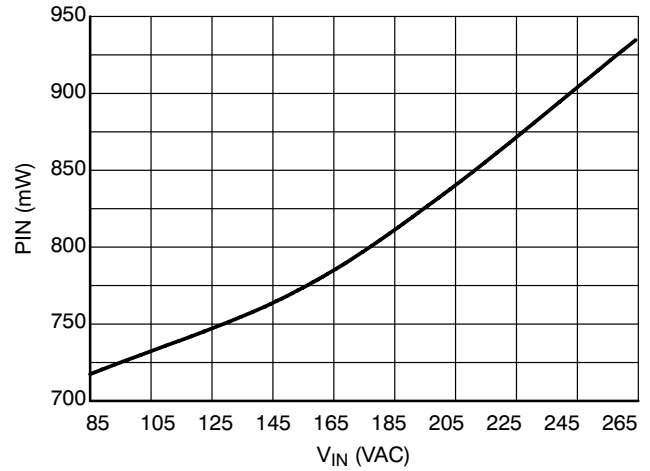


Figure 7. Standby Consumption versus Line Voltage - 0.5 W Load on STB Output

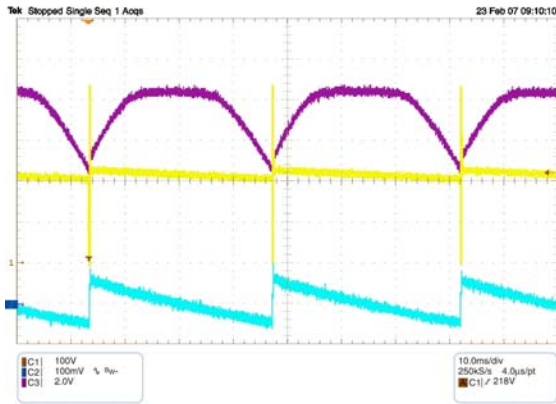


Figure 8. LLC Converter Waveforms During Skip Mode (1 - Bridge Voltage, 2 - Output Ripple on 12 V Output, 3 - Feedback Pin of the NCP1396)

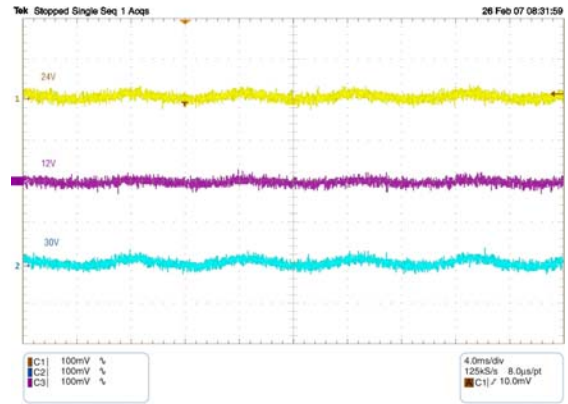


Figure 9. Output Ripple on Each LLC Stage Output for Full Load Conditions (1 - 24 V Output, 2 - 30 V Output, 3 - 12 V Output)

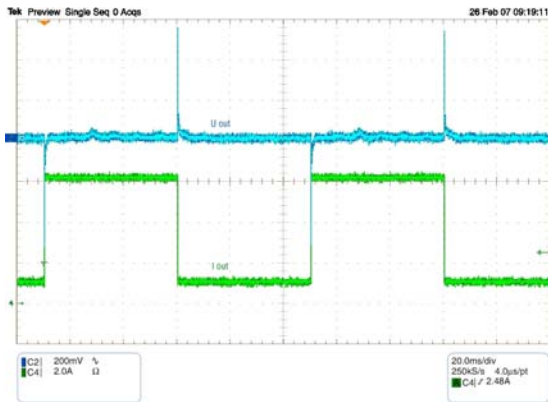


Figure 10. LLC Stage Load Regulation for 230 V Input Voltage (2 - Output Voltage on the 24 V Output, 4 - Output Current from the 24 V Output)

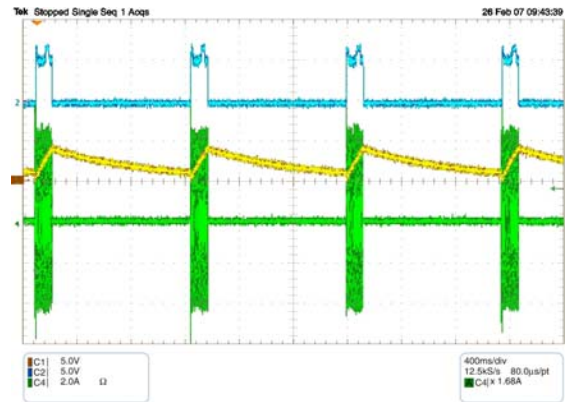


Figure 11. LLC Stage Operating Under Short Circuit (1 - Ctimer Voltage, 2 - Feedback Voltage, 4 - Primary Current)

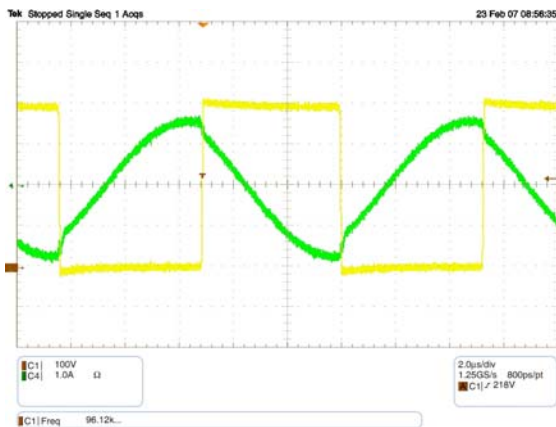


Figure 12. LLC Stage Full Load Operation (1 - Bridge Voltage, 4 - Primary Current)

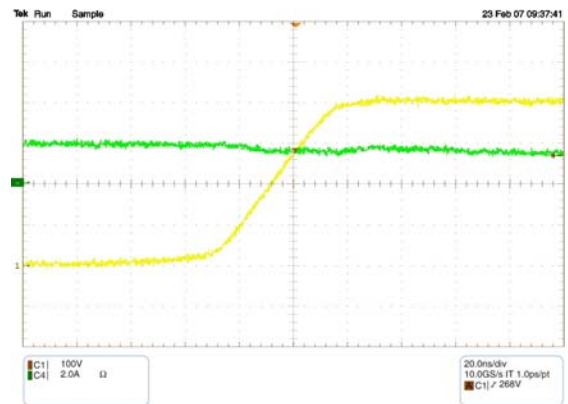


Figure 13. Detail of the ZVS Condition on the Bridge - Rising Edge (1 - Bridge Voltage, 4 - Primary Current)

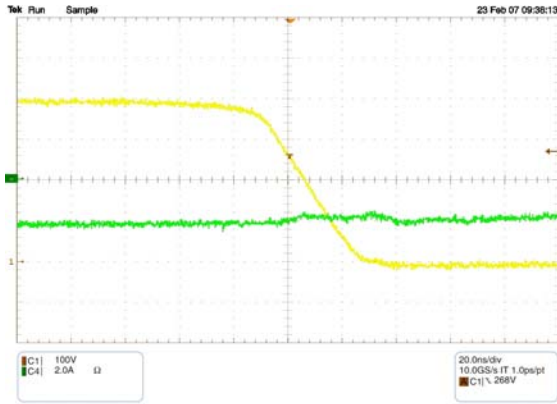


Figure 14. Detail of the ZVS Condition on the Bridge - Falling Edge (1 - Bridge Voltage, 4 - Primary Current)

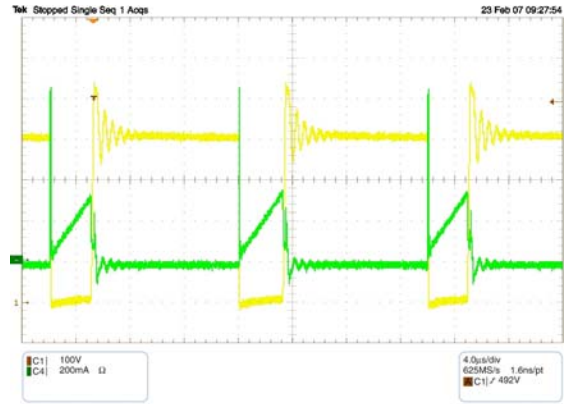


Figure 15. Standby Power Supply Waveforms - Full Loaded (1 - NCP1027 Drain Voltage, 4 - Drain Current)

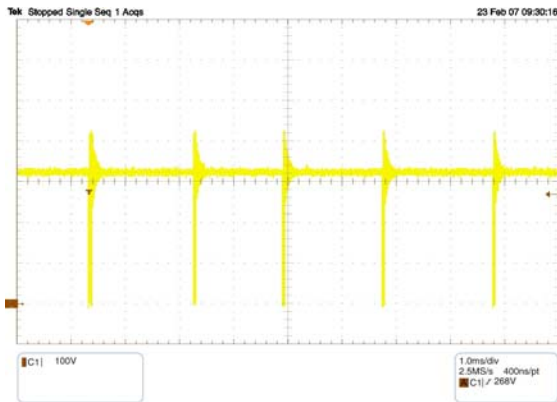


Figure 16. Standby Power Supply Waveforms - No Load Conditions (1 - NCP1027 Drain Voltage)

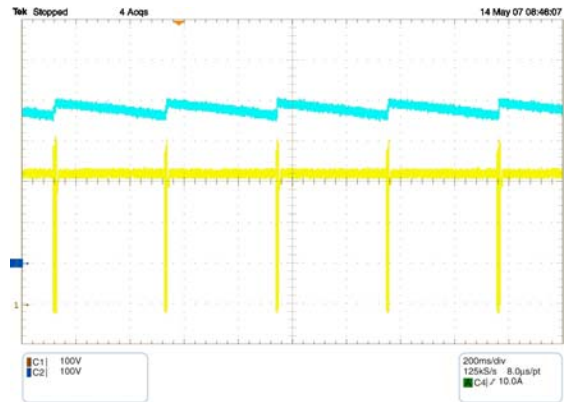


Figure 17. PFC Stage Skip Mode (1 - Q2 Drain Voltage, 2 - Bulk Voltage)

Layout Consideration

Leakage inductance on the primary side is not very critical for the LLC converter compared to other topologies, because it will only slightly modify the resonant frequency. However it is well to keep the areas of each power loop as small as possible due to radiated EMI noise. A two-sided PCB with one side ground plane helps (see Figures 21 and 23).

Thanks

I would like to thank the PULSE engineering company for provided samples and support for magnetic components used in this board.

I would also like to thank the COILCRAFT company for providing samples of the filtering inductors.

CAUTION

This demo board is intended for demonstration and evaluation purposes only and not for the end customer.

Literature

1. NCP1396A/B data sheet
2. NCP1605 data sheet
3. NCP1027 data sheet
4. Application note AND8241/D
5. Application note AND8255/D

6. Application note AND8257/D
7. Application note AND8281/D
8. Bo Yang - Topology Investigation for Front End DC-DC Power Conversion for Distributed Power System
9. M. B. Borage, S. R. Tiwari and S. Kotaiah - Design Optimization for an LCL - Type Series Resonant Converter
10. Pulse Engineering - Transformer specification, No: 2652.0017A
11. Pulse Engineering - Transformer specification, No: 2362.0031B
12. Pulse Engineering - PFC inductor specification, No: 2702.0012A

Please contact Pulse Engineering Company regarding literature 10 - 12:

Pulse European Headquarters
Einsteinstrasse 1
71083 Herrenberg
Germany

TEL: 49 7032 7806 0
FAX: 49 7032 7806 12

AND8293/D

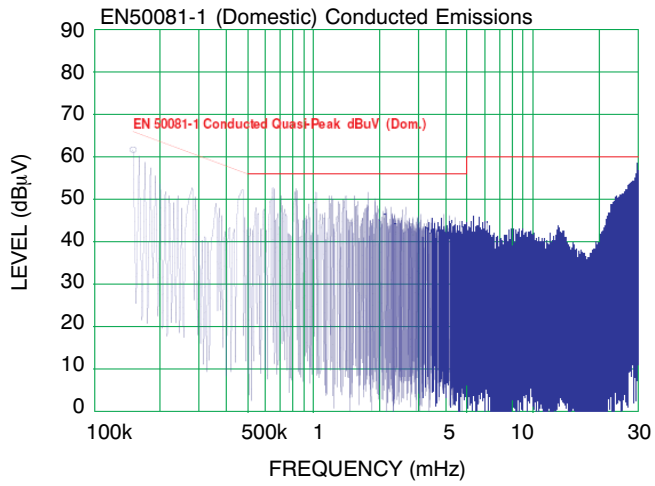


Figure 18. Conducted EMI Signature of the Board for Full Load and 230 VAC Input

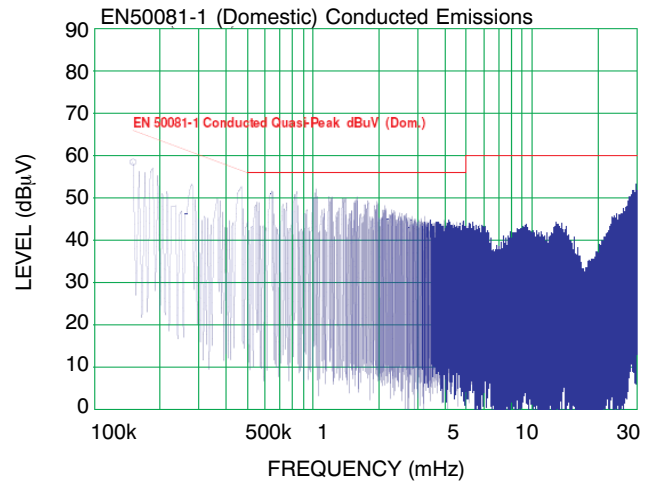


Figure 19. Conducted EMI Signature of the Board for Full Load and 110 VAC Input

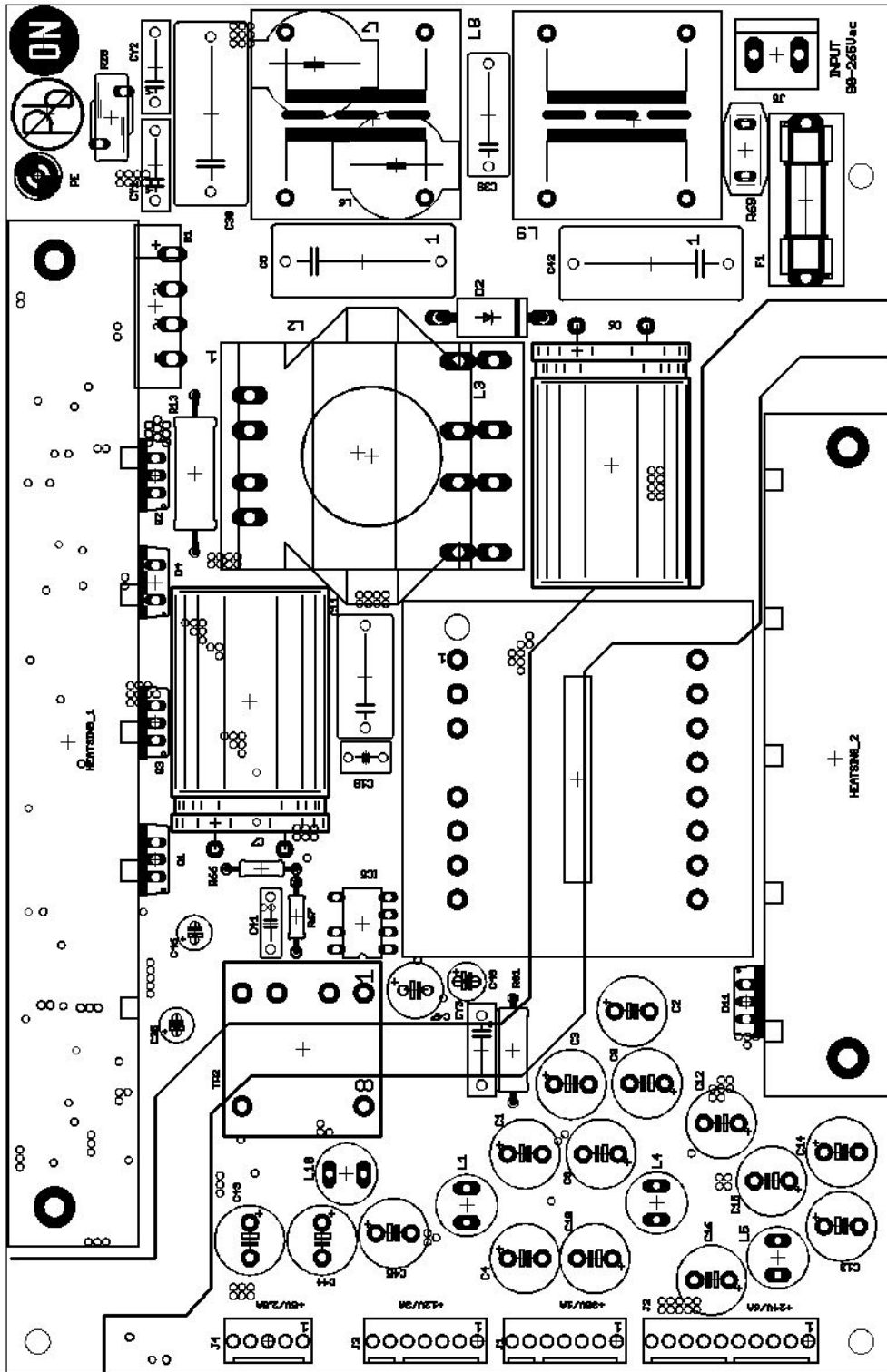


Figure 20. Component Placement on the Top Side (Top View)

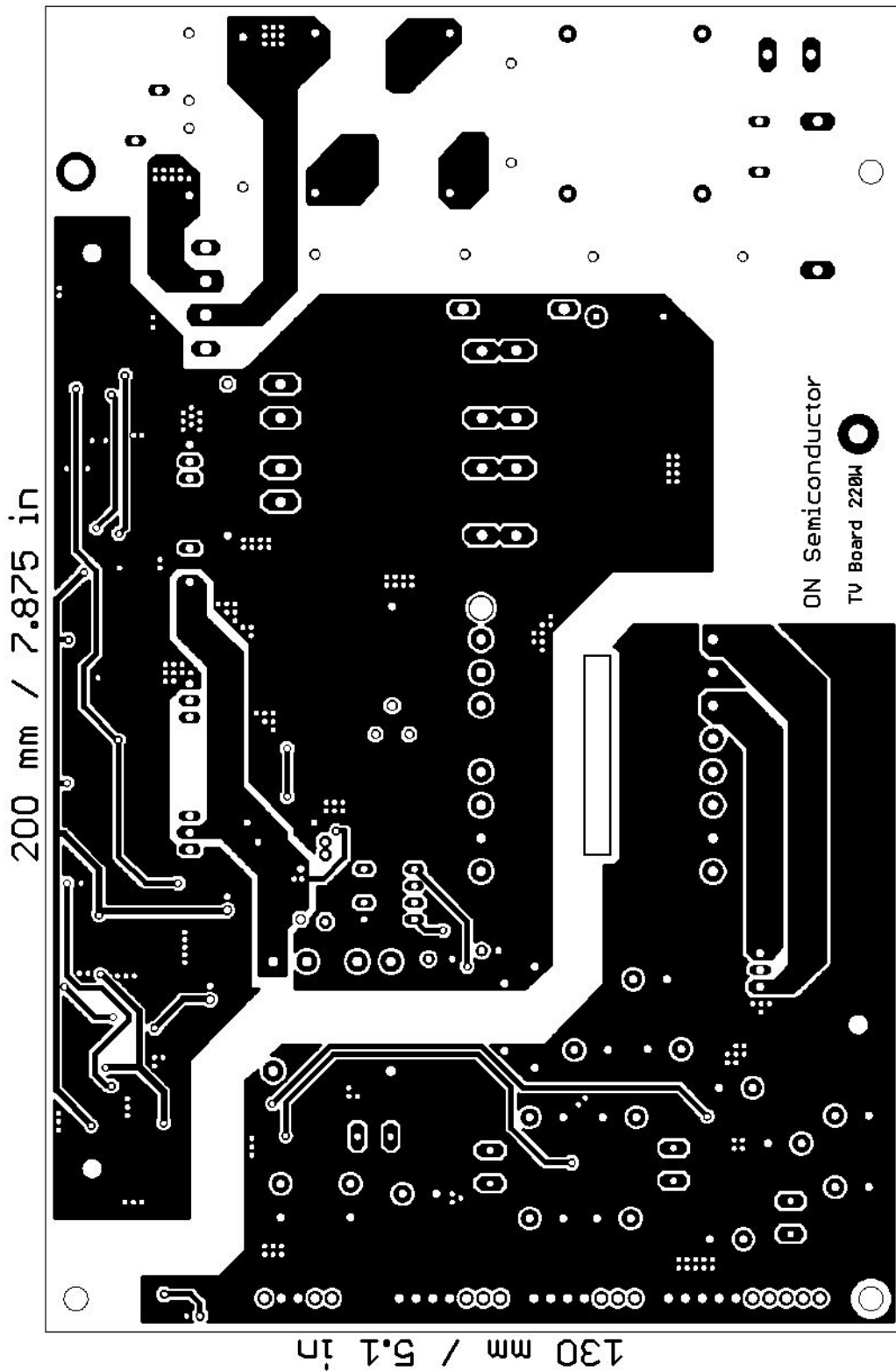


Figure 21. Top Side (Top View)

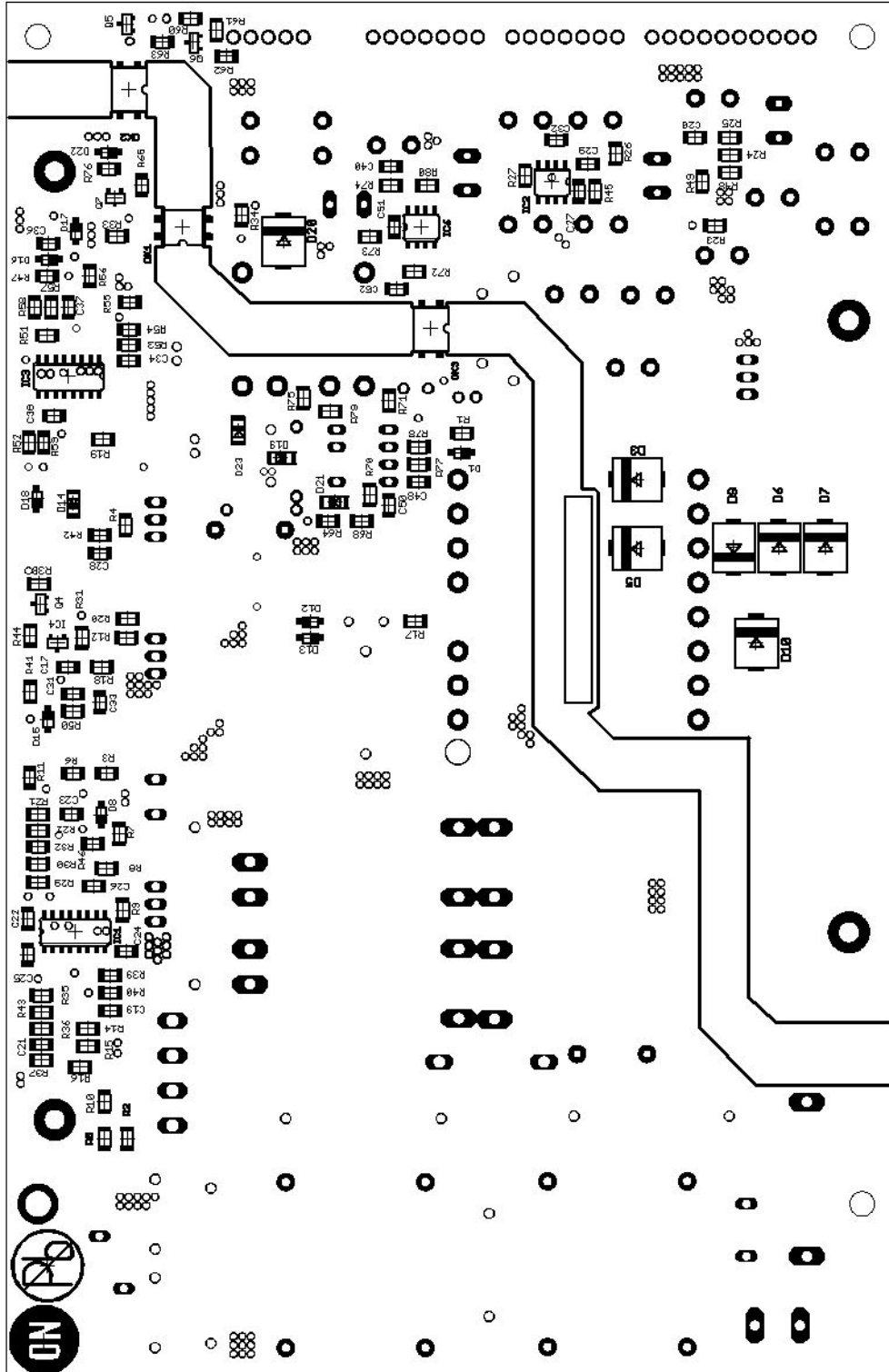


Figure 22. Component Placement on the Bottom Side (Bottom View)

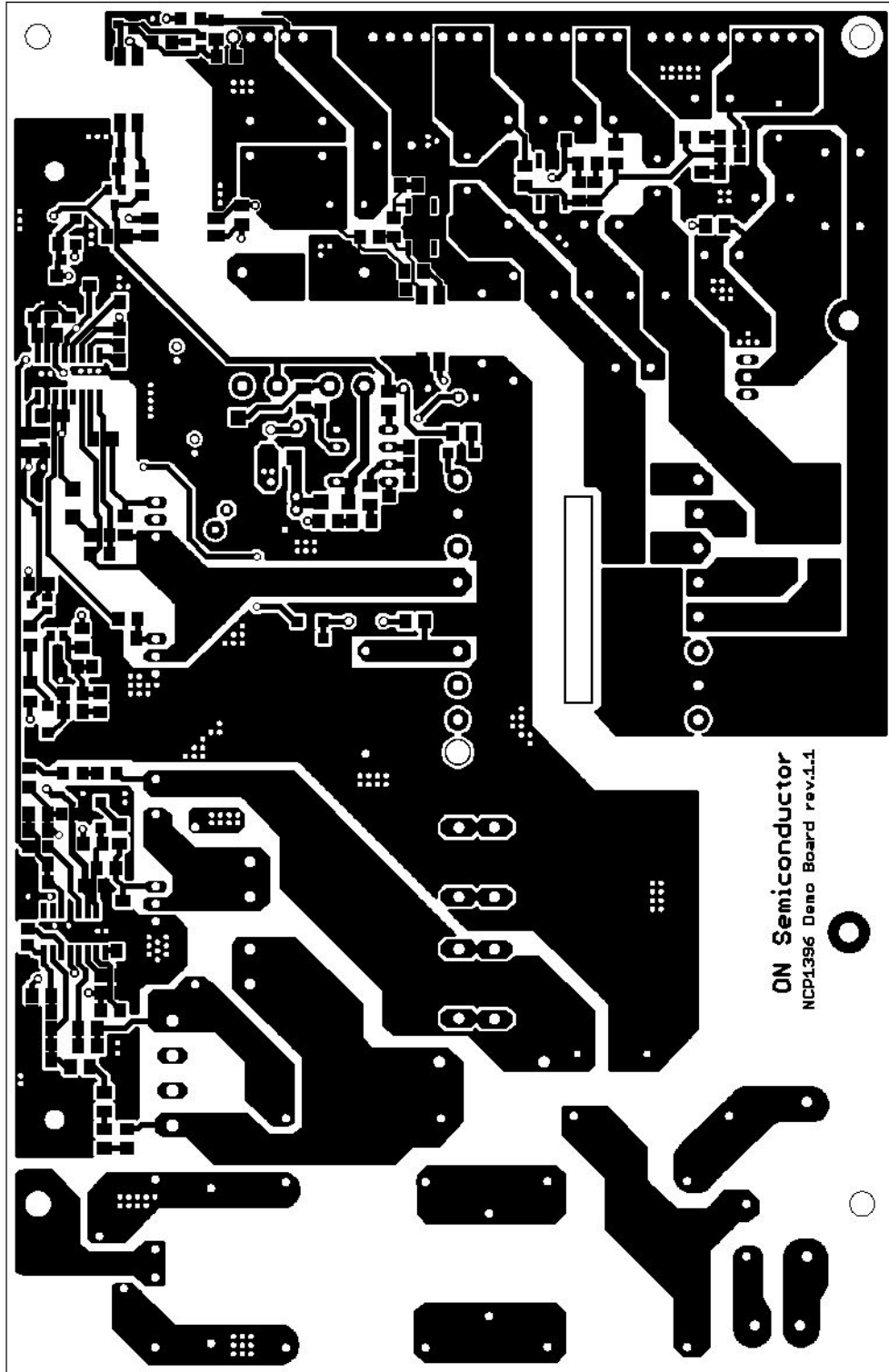


Figure 23. Bottom Side (Bottom View)

AND8293/D



Figure 24. Photo of the Designed Prototype (Real Dimensions are 200 x 130 mm)

AND8293/D

BILL OF MATERIAL

| Designator | Qty | Description | Value | Tolerance | Footprint | Manufacturer | Manufacturer Part Number |
|--|-----|------------------------|------------------|-----------|-----------------|--------------|---------------------------|
| B1 | 1 | Bridge Rectifier | KBU8M | | KBU | Fairchild | KBU8M |
| C1, C2, C3, C8, C9, C12, C13, C14, C15, C43, C44 | 11 | Electrolytic Capacitor | 470 μ F/35V | 20% | CPOL-EUE5-10.5 | Rubycon | 35ZL470M10X20 |
| C10 | 1 | Electrolytic Capacitor | 220 μ F/63V | 10% | CPOL-EUE5-10.5 | Rubycon | 63 YXA220M 10x16 |
| C11 | 1 | MKP Capacitor | 33nF/630Vdc | 20% | C-EU150-084X183 | Arcotronics | R73-0.033 μ F 15 630V |
| C16 | 1 | Electrolytic Capacitor | 220 μ F/35V | 20% | CPOL-EUE5-10.5 | Rubycon | 35 RX30220M 10x12.5 |
| C17, C48 | 2 | Ceramic Capacitor SMD | 10n | 10% | C-EUC1206 | Epcos | B37872A5103K060 |
| C18 | 1 | Ceramic Capacitor | 220p | 10% | C-EU050-045X075 | Panasonic | ECKA3A221KBP |
| C19 | 1 | Ceramic Capacitor SMD | 8n2 | 10% | C-EUC1206 | Epcos | B37872A5822K060 |
| C20, C23, C32, C33, C36, C52 | 6 | | NU | | C-EUC1206 | | |
| C21 | 1 | Ceramic Capacitor SMD | 150n | 10% | C-EUC1206 | Epcos | B37872A5154K060 |
| C22 | 1 | Ceramic Capacitor SMD | 220n | 10% | C-EUC1206 | Epcos | B37872A5224K060 |
| C24 | 1 | Ceramic Capacitor SMD | 390p | 5% | C-EUC1206 | Epcos | B37871K5391J060 |
| C25 | 1 | Ceramic Capacitor SMD | 1n2 | 10% | C-EUC1206 | Epcos | B37872A5122K060 |
| C26, C28, C38, C40, C51 | 5 | Ceramic Capacitor SMD | 100n | 10% | C-EUC1206 | Epcos | B37872A5104K060 |
| C27 | 1 | Ceramic Capacitor SMD | 1n | 10% | C-EUC1206 | Epcos | B37872A5102K060 |
| C29 | 1 | Ceramic Capacitor SMD | 22n | 10% | C-EUC1206 | Epcos | B37872A5223K060 |
| C31 | 1 | Ceramic Capacitor SMD | 68n | 10% | C-EUC1206 | Epcos | B37872A5683K060 |
| C34 | 1 | Ceramic Capacitor SMD | 1 μ F | 10% | C-EUC1206 | Epcos | B37872K0105K062 |
| C35 | 1 | Electrolytic Capacitor | 4 μ 7/35V | 20% | CPOL-EUE2-5 | Rubycon | 35 MH54.7M 4x5 |
| C37 | 1 | Ceramic Capacitor SMD | 2n2 | 10% | C-EUC1206 | Epcos | B37872A5222K060 |
| C39 | 1 | | NU | | C-EU150-064X183 | | |
| C4, C45 | 2 | Electrolytic Capacitor | 220 μ F/25V | 20% | CPOL-EUE5-10.5 | Rubycon | 25 NXA220M 10x12.5 |
| C41 | 1 | MKP Capacitor | 10nF/630Vdc | 20% | C-EU075-032X103 | Epcos | B32560J8103M000 |
| C46 | 1 | Electrolytic Capacitor | 1 μ | 20% | CPOL-EUE2-5 | Rubycon | 50 MH51M 4x5 |
| C47 | 1 | Electrolytic Capacitor | 100 μ F/35V | 20% | CPOL-EUE5.5-8 | Rubycon | 50 PK100M 8x11.5 |
| C49 | 1 | Electrolytic Capacitor | 10 μ F/35V | 20% | CPOL-EUE2.5-6 | Rubycon | 50 MH710M 6.3x7 |
| C5, C30, C42 | 3 | MKP Capacitor | 1 μ F/275Vac | 20% | C-EU225-108X268 | Arcotronics | R46KM41000N1M |
| C50 | 1 | Ceramic Capacitor SMD | 100p | 20% | C-EUC1206 | Epcos | B37871K5101J060 |

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BILL OF MATERIAL

| Designator | Qty | Description | Value | Tolerance | Footprint | Manufacturer | Manufacturer Part Number |
|-------------------------|-----|---|--------------------|-----------|---------------------------|--------------------|--------------------------|
| C6 | 1 | Electrolytic Capacitor | 100µF/450V | 20% | EC18L40'22L35' | Rubycon | 450 VXG100M 22x30 |
| C7 | 1 | Electrolytic Capacitor | 100µF/450V | 20% | EC18L40'22L35_90' | Rubycon | 450 VXG100M 22x30 |
| CY1, CY2, CY3 | 3 | Ceramic Capacitor | 2n2/Y1 | 20% | CYYC10B4 | Murata | DE1E3KX222MA5B |
| D1, D8, D12, D13, D17 | 5 | Diode | MMSD4148 | | SOD-123 | ON Semiconductor | MMSD4148T1G |
| D11 | 1 | Dual Diode | MBRF20100CT | | TO-220 | ON Semiconductor | MBRF20100CTG |
| D14, D21, D23 | 3 | Diode | MURA160SMD | | SMA | ON Semiconductor | MURA160T3G |
| D15 | 1 | Zener Diode | 3V3 | 5% | SOD-123 | ON Semiconductor | MMSZ3V3T1G |
| D16 | 1 | | NU | | SOD-123 | | |
| D18 | 1 | Zener Diode | 7V5 | 5% | SOD-123 | ON Semiconductor | MMSZ7V5T1G |
| D19 | 1 | | NU | | SMA | | |
| D2 | 1 | Diode | 1N5408 | | Axial Lead 9.50x5.30mm | ON Semiconductor | 1N5408G |
| D20 | 1 | Diode | MBRS340T3 | | SMC | ON Semiconductor | MBRS320T3G |
| D22 | 1 | Zener Diode | 18V | 5% | SOD-123 | ON Semiconductor | MMSZ18T1G |
| D3, D5, D6, D7, D9, D10 | 6 | Diode | MBRS4201T3G | | SMC | ON Semiconductor | MBRS4201T3G |
| D4 | 1 | Diode | MSR860 | | TO-220 | ON Semiconductor | MSR860G |
| F1 | 1 | FUSEHOLDER , 20X5MM | SH22, 5A | | SH22, 5A | Multicomp | MCHTC-15M |
| | 1 | COVER, PCB FUSEHOLDER | | | | Multicomp | MCHTC-150M |
| | 1 | FUSE, MEDIUM DELAY 4A | 4A | | | BUSSMANN | TDC 210-4A |
| HEATSING_1 | 1 | Heatsing | SK 454 150 SA | | SK454/150_GND | Fischer Elektronik | SK 454 150 SA |
| HEATSING_2 | 1 | Heatsing | SK 454 100 SA | | SK454/100_GND | Fischer Elektronik | SK 454 100 SA |
| IC1 | 1 | PFC Controller | NCP1605 | | SOIC 16 | ON Semiconductor | NCP1605DR2G |
| IC2, IC6 | 2 | Programmable Precision Reference | TL431SO8 | | SOIC-8 | ON Semiconductor | NCV431ADR2G |
| IC3 | 1 | Resonant Controller | NCP1396A | | SOIC 16 | ON Semiconductor | NCP1396ADR2G |
| IC4 | 1 | Programmable Precision Reference | TLV431A | | SOT-23 | ON Semiconductor | TLV431ASN1T1G |
| IC5 | 1 | HV Switcher for Medium Power Offline SMPS | NCP1027 | | PDIP (8 Minus Pin 6) | ON Semiconductor | NCP1027P065G |
| J1, J3 | 2 | Connector | 22-23-2071 | | MOLEX-7PIN | Molex | 22-23-2071 |
| J2 | 1 | Connector | 22-23-2101 | | MOLEX-10PIN | Molex | 22-23-2101 |
| J4 | 1 | Connector | 22-23-2051 | | MOLEX-5PIN | Molex | 22-23-2051 |
| J5 | 1 | Connector | LP7.5/2/903.2 OR | | Weidmueller | Weidmueller | LP7.5/2/903.2 OR |
| L1, L4, L5, L10 | 4 | Inductor | 2µ2 | 20% | RFB0807 | Coilcraft | RFB0807-2R2L |
| L2 | 1 | Inductor | 2702.0012A (260µH) | 15% | Pulse_2702 | Pulse | 2702.0012A |
| L3 | 1 | | NU | | 2722.0005A | | |
| L6, L7 | 2 | Inductor | 100µ | 20% | DO5040H_100 | Coilcraft | DO5040H-104MLB |

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BILL OF MATERIAL

| Designator | Qty | Description | Value | Tolerance | Footprint | Manufacturer | Manufacturer Part Number |
|--|-----|--------------------------------|---------------|-----------|----------------|--------------------|--------------------------|
| L8 | 1 | | NU | | TLBI | | |
| L9 | 1 | EMI Filter | 7mH | 15% | TLBI | Pulse | 6001.0069 |
| OK1, OK2, OK3 | 3 | Opto-Coupler | PC817 | | PC817SMD | Avago Technologies | HCPL-817-300E |
| Q1, Q3 | 2 | MOSFET Transistor | STP12NM50FP | | TO-220 | STMicroelectronics | STP12NM50FP |
| Q2 | 1 | MOSFET Transistor | STP20NM60FP | | TO-220 | STMicroelectronics | STP12NM50FP |
| Q4 | 1 | PNP General Purpose Transistor | BC856-16LT1 | | SOT-23 | ON Semiconductor | BC856-16LT1G |
| Q5, Q7 | 2 | NPN General Purpose Transistor | BC817-16LT1 | | SOT-23 | ON Semiconductor | BC817-16LT1G |
| Q6 | 1 | | NU | | SOT-23 | | |
| R1, R8, R19, R20 | 4 | Resistor SMD | 10R | 1% | R-EU_R1206 | Vishay | RCA120610R0FKEA |
| R13 | 1 | Resistor Trough Hole | 0.1R | 1% | R-EU_0617/22 | Vishay | PAC300001007FAC000 |
| R14 | 1 | Resistor SMD | 7k5 | 1% | R-EU_R1206 | Vishay | RCA12067K50FKEA |
| R15, R51 | 2 | Resistor SMD | 8k2 | 1% | R-EU_M1206 | Vishay | RCA12068K20FKEA |
| R17 | 1 | Resistor SMD | 47k | 1% | R-EU_M1206 | Vishay | RCA120647K0FKEA |
| R18 | 1 | Resistor SMD | 1k6 | 1% | R-EU_M1206 | Vishay | RCA12061K60FKEA |
| R2, R5, R10, R16 | 4 | Resistor SMD | 1M8 | 1% | R-EU_M1206 | Vishay | RCA12061M80FKEA |
| R21, R25, R26, R27, R37, R46, R50 | 7 | Resistor SMD | NU | 1% | R-EU_M1206 | Vishay | |
| R22 | 1 | Resistor SMD | 1k1 | 1% | R-EU_M1206 | Vishay | RCA12061K10FKEA |
| R23, R33, R34, R38, R41, R73 | 6 | Resistor SMD | 1k | 1% | R-EU_M1206 | Vishay | RCA12061K00FKEA |
| R24, R77 | 2 | Resistor SMD | 18k | 1% | R-EU_M1206 | Vishay | RCA120618K0FKEA |
| R28 | 1 | Varistor | VDRH10S275TSE | | VARISTOR10K300 | Vishay | 2381 584 T271S |
| R29 | 1 | Resistor SMD | 33k | 1% | R-EU_M1206 | Vishay | RCA120633K0FKEA |
| R3, R6, R11 | 3 | Resistor SMD | 1M3 | 1% | R-EU_R1206 | Vishay | RCA12061M30FKEA |
| R30 | 1 | Resistor SMD | 91k | 1% | R-EU_M1206 | Vishay | RCA120691K0FKEA |
| R31, R48 | 2 | Resistor SMD | 3k3 | 1% | R-EU_M1206 | Vishay | RCA12063K30FKEA |
| R32, R39, R55 | 3 | Resistor SMD | 15k | 1% | R-EU_R1206 | Vishay | RCA12061K50FKEA |
| R36 | 1 | Resistor SMD | 62k | 1% | R-EU_M1206 | Vishay | RCA120662K0FKEA |
| R4, R9, R12, R35, R43, R44, R52, R57, R61, R74, R79, R80 | 12 | Resistor SMD | 10k | 1% | R-EU_M1206 | Vishay | RCA120610K0FKEA |
| R40 | 1 | Resistor SMD | 150R | 1% | R-EU_R1206 | Vishay | RCA1206150RFKEA |
| R42 | 1 | Resistor SMD | 18R | 1% | R-EU_R1206 | Vishay | RCA120618R0FKEA |
| R45 | 1 | Resistor SMD | 2k7 | 1% | R-EU_M1206 | Vishay | RCA12062K70FKEA |
| R47 | 1 | Resistor SMD | 2k2 | 1% | R-EU_R1206 | Vishay | RCA12062K20FKEA |
| R49 | 1 | Resistor SMD | 5k6 | 1% | R-EU_M1206 | Vishay | RCA12065K60FKEA |
| R53 | 1 | Resistor SMD | 24k | 1% | R-EU_R1206 | Vishay | RCA120624K0FKEA |


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BILL OF MATERIAL

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|--|-----|------------------------------------|-------------|-----------|-----------------|--------------|--------------------------|
| R54 | 1 | Resistor SMD | 150k | 1% | R-EU_R1206 | Vishay | RCA1206150KFKEA |
| R56 | 1 | Resistor SMD | 6k8 | 1% | R-EU_R1206 | Vishay | RCA12066K80FKEA |
| R58 | 1 | Resistor SMD | 1k5 | 1% | R-EU_R1206 | Vishay | RCA12061K50FKEA |
| R59 | 1 | Resistor SMD | 6k2 | 1% | R-EU_R1206 | Vishay | RCA12066K20FKEA |
| R60, R62, R63 | 3 | Resistor SMD | 820R | 1% | R-EU_R1206 | Vishay | RCA1206820RFKEA |
| R64, R68 | 2 | Resistor SMD | 1M2 | 1% | R-EU_R1206 | Vishay | RCA12061M20FKEA |
| R65 | 1 | Resistor SMD | 4k7 | 1% | R-EU_R1206 | Vishay | RCA12064K70FKEA |
| R66 | 1 | Resistor Trough Hole | 150k | 1% | R-EU_0207/10 | Vishay | MRS25000C1503FCT |
| R67 | 1 | Resistor Trough Hole | 47R | 1% | R-EU_0207/10 | Vishay | MRS25000C4709FCT |
| R69 | 1 | Option for Thermistor | 0R0 | | P594 | | |
| R7 | 1 | Resistor SMD | 0R0 | 1% | R-EU_M1206 | Vishay | RCA12060000FKEA |
| R70 | 1 | Resistor SMD | 180k | 1% | R-EU_M1206 | Vishay | RCA1206180KFKEA |
| R71 | 1 | Resistor SMD | 3k9 | 1% | R-EU_M1206 | Vishay | RCA12063K90FKEA |
| R72 | 1 | Resistor SMD | 100R | 1% | R-EU_M1206 | Vishay | RCA1206100RFKEA |
| R75 | 1 | Resistor SMD | 360k | 1% | R-EU_M1206 | Vishay | RCA1206360KFKEA |
| R76 | 1 | Resistor SMD | 470k | 1% | R-EU_R1206 | Vishay | RCA1206470KFKEA |
| R78 | 1 | Resistor SMD | 75k | 1% | R-EU_M1206 | Vishay | RCA120675K0FKEA |
| R81 | 1 | Resistor Trough Hole, High Voltage | 4M7 | 5% | R-EU_0414/15 | Vishay | VR37000004704JA100 |
| TR1 | 1 | Resonant Transformer | 2652.0017A | 15% | 2652 | Pulse | 2652.0017A |
| TR2 | 1 | Standby Transformer | 2362.0031B | 15% | 2362 | Pulse | 2362.0031B |
| B1 | 1 | Bridge Rectifier | KBU8M | | KBU | Fairchild | KBU8M |
| C1, C2, C3, C8, C9, C12, C13, C14, C15, C43, C44 | 11 | Electrolytic Capacitor | 470µF/35V | 20% | CPOL-EUE5-10.5 | Rubycon | 35ZL470M10X20 |
| C10 | 1 | Electrolytic Capacitor | 220µF/63V | 10% | CPOL-EUE5-10.5 | Rubycon | 63 YXA220M 10x16 |
| C11 | 1 | MKP Capacitor | 33nF/630Vdc | 20% | C-EU150-084X183 | Arcotronics | R73-0.033uF 15 630V |
| C16 | 1 | Electrolytic Capacitor | 220µF/35V | 20% | CPOL-EUE5-10.5 | Rubycon | 35 RX30220M 10x12.5 |
| C17, C48 | 2 | Ceramic Capacitor SMD | 10n | 10% | C-EUC1206 | Epcos | B37872A5103K060 |

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